## **MMBV3401LT1G**

# Silicon Pin Diode

This device is designed primarily for VHF band switching applications but is also suitable for use in general-purpose switching circuits. Supplied in a Surface Mount package.

#### **Features**

- Rugged PIN Structure Coupled with Wirebond Construction for Optimum Reliability
- Low Capacitance 0.7 pF (Typ) at  $V_R = 20 \text{ Vdc}$
- Very Low Series Resistance at 100 MHz
   0.34 Ω (Typ) @ I<sub>F</sub> = 10 mAdc
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	35	Vdc
Forward Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	200 2.0	mW mW/°C
Junction Temperature	TJ	+125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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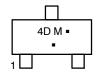
http://onsemi.com





SOT-23 (TO-236AB) CASE 318-08 STYLE 8

## **MARKING DIAGRAM**



4D = Device Code

M = Date Code\*

Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBV3401LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBV3401LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Downloaded from Arrow.com.

## MMBV3401LT1G

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage ( $I_R = 10 \mu Adc$ )	V <sub>(BR)R</sub>	35	-	-	Vdc
Diode Capacitance (V <sub>R</sub> = 20 Vdc)	C <sub>T</sub>	-	-	1.0	pF
Series Resistance (Figure 1) (I <sub>F</sub> = 10 mAdc, f = 100 MHz)	R <sub>S</sub>	-	-	0.7	Ω
Reverse Leakage Current (V <sub>R</sub> = 25 Vdc)	I <sub>R</sub>	-	-	0.1	μAdc

## TYPICAL CHARACTERISTICS

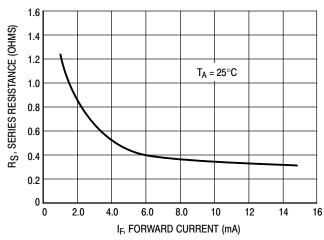


Figure 1. Series Resistance

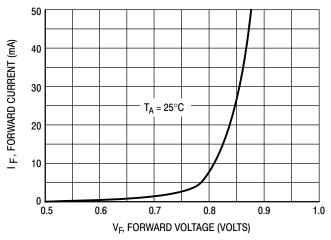


Figure 2. Forward Voltage

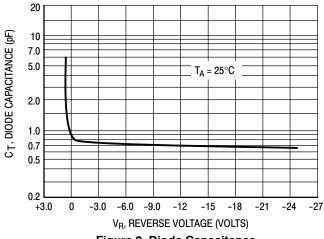


Figure 3. Diode Capacitance

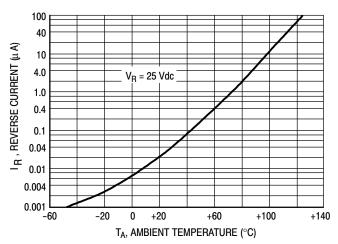


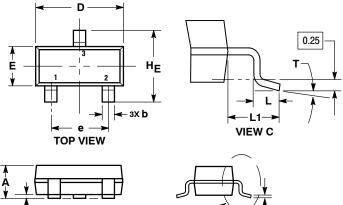
Figure 4. Leakage Current



SOT-23 (TO-236) CASE 318-08 **ISSUE AS** 

**DATE 30 JAN 2018** 

# SCALE 4:1



SEE VIEW C

**END VIEW** 

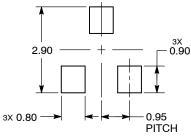
#### NOTES:

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
  MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	М	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.039	0.044	
A1	0.01	0.06	0.10	0.000	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.017	0.020	
С	0.08	0.14	0.20	0.003	0.006	0.008	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.080	
L	0.30	0.43	0.55	0.012	0.017	0.022	
L1	0.35	0.54	0.69	0.014	0.021	0.027	
HE	2.10	2.40	2.64	0.083	0.094	0.104	
T	0°		10°	0°		10°	

## **RECOMMENDED SOLDERING FOOTPRINT**

SIDE VIEW



2. ANODE

STYLE 27: PIN 1. CATHODE 2. CATHODE

3. CATHODE

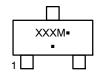
DIMENSIONS: MILLIMETERS

2. SOURCE

STYLE 28: PIN 1. ANODE 2. ANODE

3. ANODE

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

STYLE 13: PIN 1. SOURCE

2. DRAIN

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ON
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	

3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE

2. CATHODE

2. CATHODE

PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	NO CONNECTION	PIN 1.	NO CONNECTION	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	CATHODE	2.	CATHODE	2.	ANODE	2.	CATHODE	2.	ANODE	2.	ANODE
3.	ANODE	3.	CATHODE	3.	CATHODE	3.	ANODE	3.	CATHODE-ANODE	3.	GATE

STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
<ol><li>SOURCE</li></ol>	<ol><li>OUTPUT</li></ol>	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
<ol><li>DRAIN</li></ol>	<ol><li>INPUT</li></ol>	<ol><li>CATHODE</li></ol>	3. SOURCE	3. GATE	<ol><li>NO CONNECTION</li></ol>

Γ		SOT-23 (TO-236)		PAGE 1 OF 1
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STYLE 14: PIN 1. CATHODE

2. GATE

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